US006312558B2

(12) **United States Patent**
Moore

(10) **Patent No.: US 6,312,558 B2**
(45) **Date of Patent: Nov. 6, 2001**

(54) **METHOD AND APPARATUS FOR PLANARIZATION OF A SUBSTRATE**

(75) Inventor: **Scott E. Moore**, Meridian, ID (US)

(73) Assignee: **Micron Technology, Inc.**, Boise, ID (US)

(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.

(21) Appl. No.: **09/782,442**

(22) Filed: **Feb. 13, 2001**

Related U.S. Application Data

(62) Division of application No. 09/172,950, filed on Oct. 14, 1998, now Pat. No. 6,187,681.

(51) **Int. Cl.**[7] **C23F 1/02**
(52) **U.S. Cl.** **156/345**; 438/591; 451/285; 451/288
(58) **Field of Search** 155/345; 438/591–593; 451/314, 388, 288, 258, 514, 515, 532, 533

(56) **References Cited**

U.S. PATENT DOCUMENTS

4,313,284 *	2/1982	Walsh	51/131.4
4,450,652	5/1984	Walsh	51/131.4
5,154,021	10/1992	Bombardier et al.	51/262
5,245,794	9/1993	Salugsugan	51/165.74
5,299,393	4/1994	Chandler et al.	51/272
5,399,234	3/1995	Yu et al.	156/636
5,413,941	5/1995	Koos et al.	437/8
5,456,627	10/1995	Jackson et al.	451/11
5,624,299	4/1997	Shendon	451/28
5,643,053 *	7/1997	Shendon	451/28
5,643,061	7/1997	Jackson et al.	451/289
5,681,215	10/1997	Sherwood et al.	451/388
5,788,560 *	8/1998	Hashimototo et al.	451/288
5,791,975 *	8/1998	Cesna et al.	451/63
5,820,448	10/1998	Shamouilian et al.	451/287
5,833,519	11/1998	Moore	451/56
5,865,666	2/1999	Nagahara	451/10
5,938,512 *	8/1999	Takei et al.	451/388

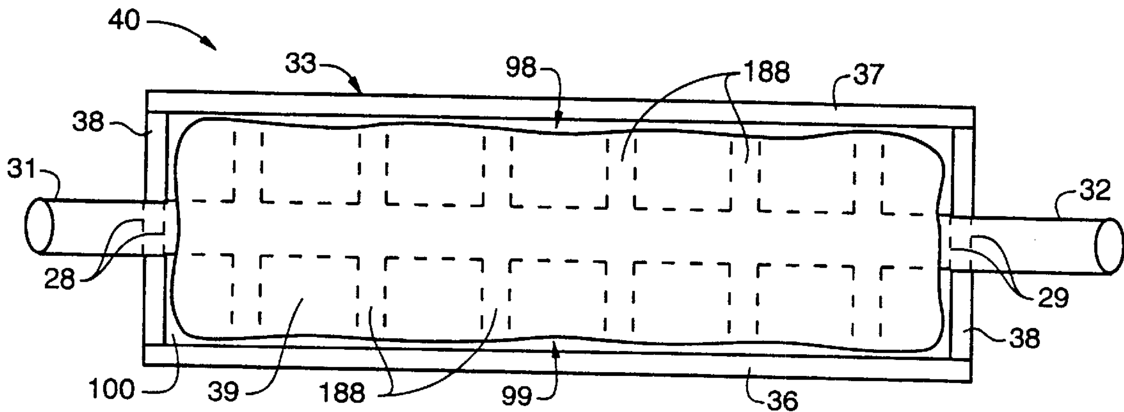
* cited by examiner

Primary Examiner—Benjamin L. Utech
Assistant Examiner—Duy-Vu Deo
(74) *Attorney, Agent, or Firm*—Schwegman, Lundberg, Woessner & Kluth, P.A.

(57) **ABSTRACT**

Method and apparatus for a chemical-mechanical-polishing (CMP) support pad structure are described. The support pad structure is made with a housing to hold an open-cell material and a fluid. The fluid is supplied in a gaseous and/or a liquid state to affect rigidity of the pad. By controlling rigidity, material removal rates may be directly affected during CMP processing. Moreover, fluid flow through the support pad structure may be regulated to adjust temperature during CMP processing.

23 Claims, 3 Drawing Sheets



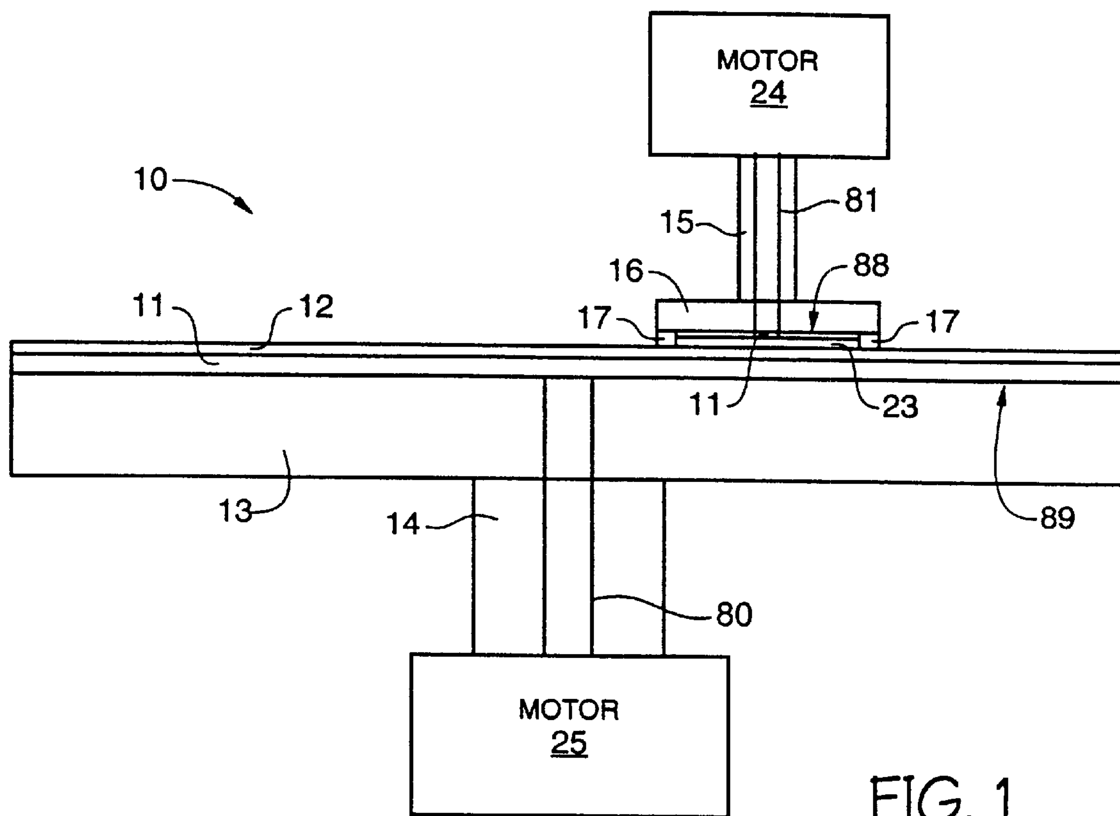


FIG. 1

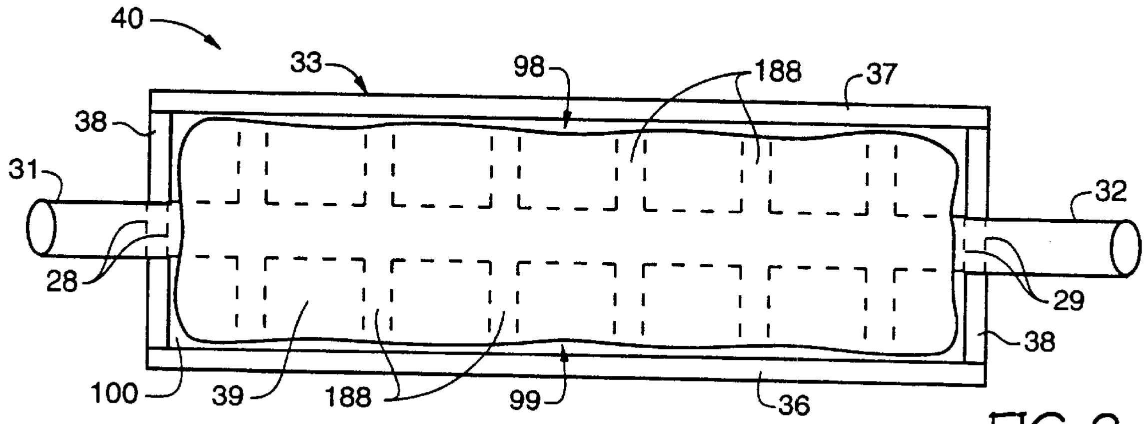


FIG. 2

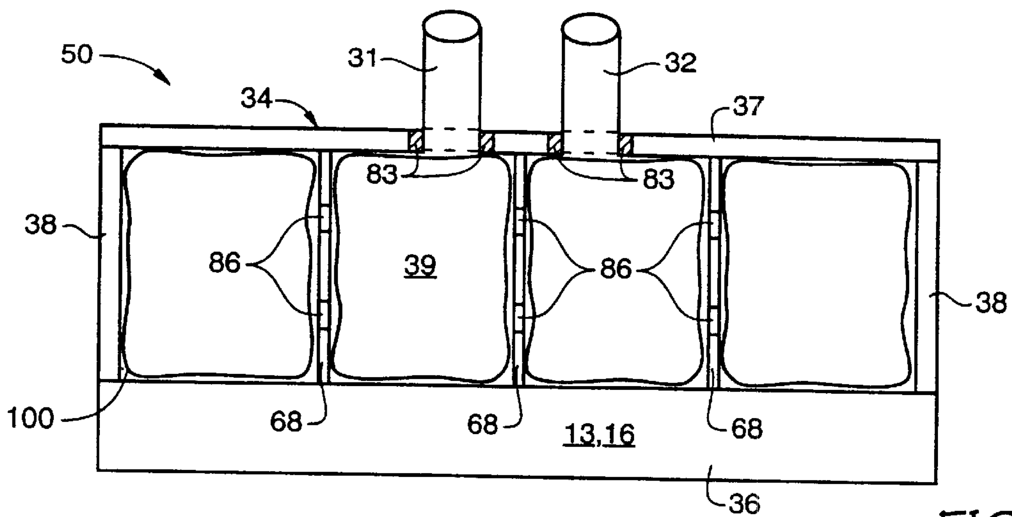


FIG. 3

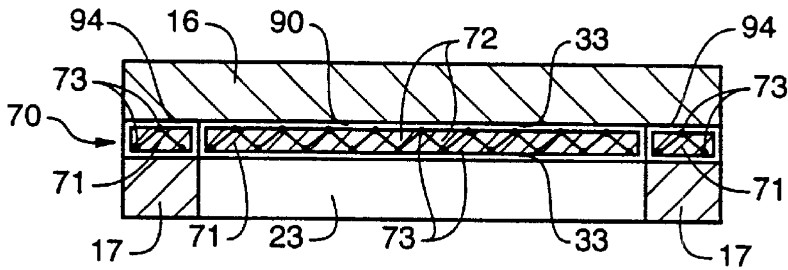


FIG. 4

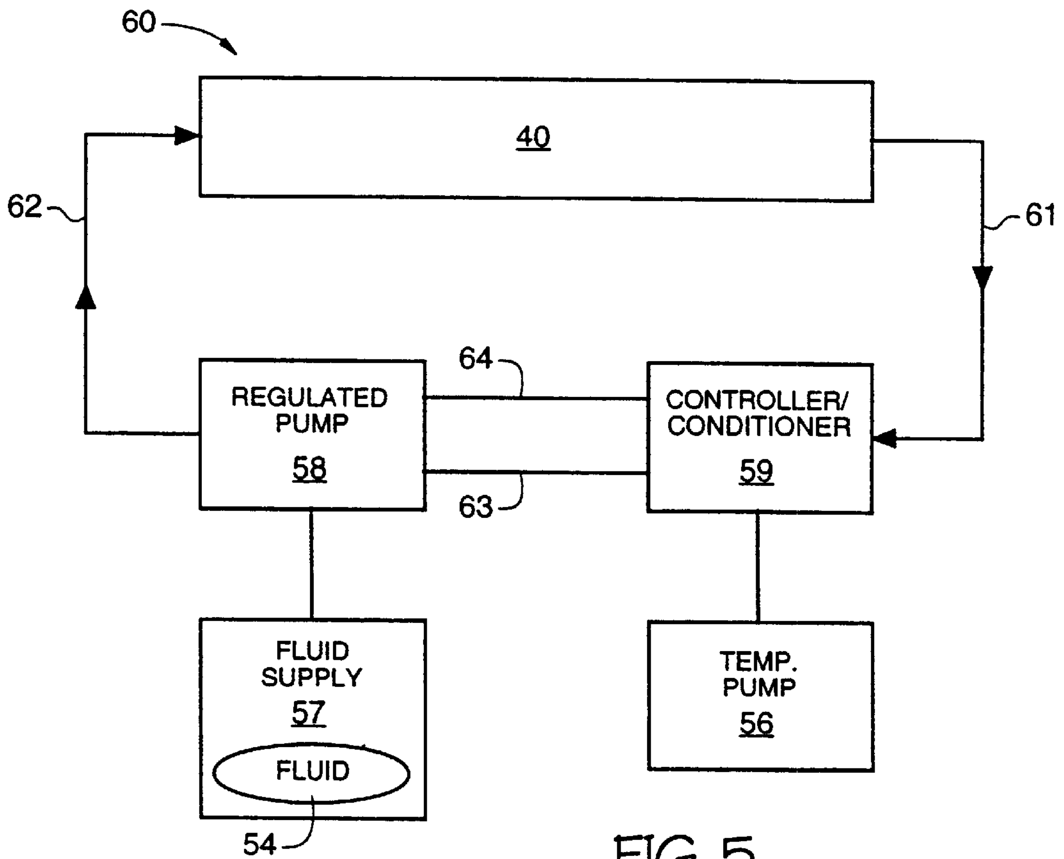


FIG. 5

METHOD AND APPARATUS FOR PLANARIZATION OF A SUBSTRATE

This application is a Divisional of U.S. application Ser. No. 09/172,950, filed Oct. 14, 1998 now U.S. Pat. No. 6,187,681.

TECHNICAL FIELD OF THE INVENTION

The present invention relates generally to mechanical polishing of a semiconductor substrate, and more particularly to a support pad for use in chemical-mechanical-polishing to planarize a substrate assembly.

BACKGROUND OF THE INVENTION

In the semiconductor industry, a technology known as chemical-mechanical-polishing ("CMP") has been developed. In "CMP," a semiconductor wafer is place between a polishing pad and a wafer carrier. The wafer carrier is a mechanical device used to provide rotation of and downward pressure on the semiconductor wafer. In this manner, the semiconductor wafer is forcibly held and rotated against the polishing pad. As a result, material is abraded from the surface of the semiconductor wafer in contact with the polishing pad.

Slurry, a liquid chemical composition generally containing particulate, may be dispensed on the polishing pad. The slurry conventionally is chemically active to remove unwanted material from the semiconductor wafer. This chemical activity may be changed during CMP processing. The slurry particulate facilitates abrasion. Alternatively, the semiconductor wafer is polished without slurry by using a "fixed-abrasive polishing pad." A "fixed-abrasive polishing pad" has protrusions formed on it to facilitate abrasion. The semiconductor wafer is thus held and rotated against the protrusions on the fixed-abrasive polishing pad.

Aside from removing unwanted material, CMP may be used to planarize a surface of a semiconductor wafer. A uniform planar surface is important for subsequent lithographic processing of the semiconductor wafer, mainly due to depth of focus limitations of lithographic equipment. Accordingly, to achieve a substantially uniformly planar surface, it is important to apply pressure uniformly. A problem has been a lack of uniform pressure resulting in a non-uniform planar surface (e.g., a wedge-like shape).

One approach to achieve greater pressure uniformity has been to place an underpad below the polishing pad. The underpad has more give than the polishing pad, and thus it distributes downward force from the wafer carrier more uniformly. However, conditions, such as temperature, applied force, and friction, change during CMP, and an underpad is not able to compensate for these changes.

Another approach to achieve a more uniform downward force has been to use a wafer carrier having multiple bellows located between a wafer carrier housing and a wafer carrier base, as is described in U.S. Pat. No. 5,681,215 to Sherwood et al. As the semiconductor wafer is held between the polishing pad and the wafer carrier base, by pressurizing bellows against the wafer carrier housing, force is directed onto the wafer carrier base, which in turn pushes down on the semiconductor wafer. As each bellows may be separately pressurized, downward force is supposedly adjustable from location to location to improve uniformity; however, Sherwood et al is a mechanically complicated approach.

Therefore, it would be desirable to have a CMP apparatus that is less mechanically complicated than Sherwood et al,

but allows for rigidity adjustment unlike present day underpads. Furthermore, it would be desirable to have a CMP apparatus that is a disposable item like an underpad.

SUMMARY OF THE INVENTION

The present invention provides method and apparatus for CMP with a support pad to provide a more uniform application of force to polish a semiconductor substrate. Such a support pad is formed with a housing. The housing defines a volume in which an open-cell material, disposed in the volume, is coupled to the housing to limit deformation of the volume. A fluid is disposed in the volume to affect rigidity of the support pad. The fluid may be in a gaseous and/or a liquid state and may be pressurized.

The housing may be attached to or in contact with a CMP wafer carrier, a CMP platen, and/or a CMP polishing pad. Such a CMP wafer carrier, platen, and/or pad may be used in combination with the housing in defining a volume in which an open-cell material and fluid is contained. Moreover, inlet and outlet tubes may be employed for providing the fluid in and out of the volume. Such ingress and egress of fluid may be used for thermal control. Baffling or webbing may be located within the volume to regulate fluid flow to maintain pressurization, and/or to limit volume deformation.

A support pad in accordance with the present invention may be a sealed unit to better cope with a harsh CMP environment; such a support pad may easily be removed and replaced. Moreover, a sealed pad may be pressurized to a desired level for a CMP operation. Alternatively, one or more tubes may be employed for in situ maintenance and/or adjustment of support pad rigidity.

BRIEF DESCRIPTION OF THE DRAWING(S)

Features and advantages of the present invention will become more apparent from the following detailed description of the preferred embodiment(s) described below in detail with reference to the accompanying drawings where:

FIG. **1** is a cross-sectional view of an exemplary portion of a CMP systems in accordance with the present invention.

FIG. **2** is a cross-sectional view of an exemplary portion of an embodiment of a support pad structure in accordance with the present invention.

FIG. **3** is a cross-sectional view of an exemplary portion of an alternate embodiment of support pad structure in accordance with the present invention.

FIG. **4** is a cross-sectional view of an exemplary portion of a wafer carrier assembly in accordance with the present invention.

FIG. **5** is a block diagram of an exemplary portion of an embodiment of a fluid control system in accordance with the present invention.

Reference numbers refer to the same or equivalent parts of embodiment(s) of the present invention throughout the several figures of the drawing.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENT(S)

Referring to FIG. **1**, there is shown a cross-sectional view of an exemplary portion of a CMP system **10**. CMP system **10** comprises motors **24** and **25**, support pads **11**, drive shafts **14** and **15**, polishing pad **12**, platen **13**, wafer carrier housing **16**, and retaining ring **17**. Motors **24** and **25** may be employed to rotatively drive shafts **15** and **14**, respectively.

Drive shafts **14** and **15** may be hollow, such that cavities, as indicated by dashed lines **80** and **81**, may house tubing to transport fluids to and from support pads **11**, as will become apparent.

A support pad **11**, in accordance with the present invention, may be located below polishing pad **12**, and/or between wafer carrier **16** and substrate assembly **23**. By "substrate assembly," it should be understood to include a bare substrate or wafer, as well as a substrate having one or more layers and/or features formed thereon and/or therein.

Several embodiments of support pads **11** are explained in more detail below, where it will become apparent that by employing a support pad of the present invention, a substantially uniformly distributed pressure may be obtained.

Referring now to FIG. **2**, there is shown a cross-sectional view of an exemplary portion of an embodiment of a support pad **40** in accordance with the present invention. Support pad **40** comprises a non-rigid housing **33**, filler **39**, inlet tube **31** and outlet tube **32**.

In defining volume **100**, housing **33** comprises upper layer **37**, lower layer **36**, and at least one outer or side layer **38**. Layers **36**, **37**, and **38** may be made from polycarbonate, polyurethane, or other suitable material. Upper layer **37** includes inner top surface **98**, and bottom layer **36** includes inner bottom surface **99**. Layers **36** and **37** may be bonded, clamped, fused, glued, epoxied, and in like manner attached or coupled to layer **38**, filler **39**, and/or webbing **68** (shown in FIG. **3**) to limit ballooning of volume **100** and/or housing **33**. Alternatively, layers **36**, **37**, and **38** may be integrally formed as one unitized housing **33**. Filler **39** may be formed after at least partial formation of housing **33** in order to substantially fill volume **100**. Alternatively, filler **39** may be prefabricated for fitting into volume **100**. Filler **39** may be formed of an open-cell material. By open-cell material, it is meant a matrix having adjacent, suspended voids ("open-cells"). In accordance with an embodiment of the present invention, matrix with embedded voids is gas or liquid permeable, and more particularly is capable of providing at least one conduit for transmitting a fluid from a proximal surface to a distal surface. Materials used in forming open-cell structures include polymers, monomers, elastomers, carbon, silicon. Some materials for forming open-cell material include polyurethane, polypropylene, polyethylene, polyolefin, polychloroprene, rubber, synthetic-rubber, among others. Each substance may be used in forming a sponge-like material as is well known. An open-cell foam with sufficient rigidity to withstand downward polish force may be employed.

Inlet tube **31** and/or outlet tube **32** may be removed or omitted where support pad **40** has a sealed volume, as indicated by dash lines **28** and **29**. For example, inlet tube **31** may be used for dispensing a fluid into volume **100** defined by housing **33**. After such dispensing is completed, inlet tube **31** may be sealed (fused, glued, epoxies, bonded, and the like) to form a sealed volume. A sealed volume support pad may be more beneficial for implementations where it is rotated during CMP.

With reference to FIG. **1**, hollow drive shafts **14**, **15** may meet holes in platen **13** and/or wafer carrier **16**, as indicated by dashed lines **80** and **81**. Such configurations may be employed at least in part to house one or more tubes **31** and/or **32**.

Inlet tube **31** and outlet tube **32** may comprise one or more tubes for transporting fluid to and from volume **100**. Furthermore, inlet tube **31** and outlet tube **32** in combination may form a manifold having one or more tubing branches or alternatively open-cell material may be configured to provide a manifold, as illustratively indicated by dashed lines **188**.

Referring to FIG. **3**, there is shown a cross-sectional view of an exemplary portion of an alternate embodiment of a support pad **50** in accordance with the present invention. Support pad **50** is similar to support pad **40** of FIG. **2**, except bottom layer **36** has been omitted, webbing **68** has been added to form baffles, and tubes **31** and **32** have been reoriented. Bottom layer **36** may be omitted in place of top surface **89** of platen **13** and/or bottom surface **88** of wafer carrier **16** (shown in FIG. **1**). Outer layer **38** is attached to platen layer **13** and/or wafer carrier **16** depending on configuration to be employed. Webbing **68**, which may have passages **86**, may be used to limit deformation of volume **100**, to regulate or direct fluid flow, and/or to maintain pressurization of filler **39**. Tubes **31** and **32** may be at least partially housed in either drive shaft **14** or **15** (shown in FIG. **1**). Seals **83** may be employed to limit or prevent fluid leakage.

Referring to FIG. **4**, there is shown a cross-sectional view of an exemplary portion of an embodiment of a wafer carrier assembly **70** in accordance with the present invention. Wafer carrier assembly **70** includes an alternate embodiment of a sealed support pad **90** of the present invention. Open-cell foam **71** may have a skin forming at least a portion of housing **94** of sealed support pad **90**. Alternatively, open-cell foam **71** may be laminated at least in part to form at least a portion of housing **94**. Also, corrugated webbing **72** may be used to form baffles to limit deformation of housing **94**. Webbing **72** may be attached to interior surfaces of housing **94** at one or more contact points **73**.

Referring now to FIG. **5**, there is shown a block diagram of an exemplary portion of an embodiment of fluid control system **60** for use with support pad **40** in accordance with the present invention. Fluid is supplied from fluid supply **57** to pump **58**. Fluid is pumped from pump **58** along in-feed tubing **62** to support pad **40**, e.g., through inlet tube **31** (shown in FIG. **2**).

Exiting fluid flows from support pad **40**, through out-feed tubing **61** to controller-conditioner **59**. Controller-conditioner **59** may be used to monitor fluid pressure and/or temperature. If temperature is too high or too low, controller-conditioner **59** may divert fluid to temperature pump **56** in order to increase or decrease temperature of fluid **54**. In this manner, support pad **40** may be employed at least in part for temperature control during CMP. Controller-conditioner **59** in electrical communication with regulated pump **58** via path **63** may regulate pressure of fluid supplied to support pad **40**. Pressure may then be referenced to absolute pressure, atmospheric pressure, or polish downward force. In one embodiment, pressure ranges from approximately 1 to 100 p.s.i. However, while not wishing to be bound by any particular theory, it is believed that the pressure should be selected to be greater than the polish downward force being applied. As CMP downward force is typically in a range of approximately 1 to 10 p.s.i., a pressure in a range of approximately 2 to 20 p.s.i. may be employed therefor. Tubing **64** allows fluid **54** transfer between controller/conditioner **59** and pump **58**.

Notably, the present invention may also be employed in a single-ended system. In which system, in-feed tubing **62** is used for ingress and egress of fluid **54** to support pad **40**, and out-feed tubing **61** is omitted.

Support pad **40** rigidity may be controlled at least in part by pressurization of volume **100** (shown in FIG. **2**) by fluid

54. Rigidity of support pad **40** may also be effected by the type of fluid selected. Fluid **54** may be in a liquid state, a colloidal (gelatinous) state, and/or a gaseous state. Moreover, gas may be introduced and at least partially dissolved in a liquid to adjust compressibility. Also, a support pad **11** (shown in FIG. **1**) may be pressurized to volumetrically expand to maintain substrate assembly **23** in contact with CMP pad **12** for polishing.

In accordance with the present invention, during CMP, support pad rigidity may be controlled to affect material removal rate. Generally, a more rigid support pad will aid removal of more material than a less rigid support pad. Also, by controlling fluid flow through a support pad, temperature may be adjusted during CMP processing, including adjustment. Also, a support pad may be pressurized to compensate for changes in a downwardly directed force used in polishing a substrate assembly.

The present invention has been particularly shown and described with respect to certain preferred embodiments(s). It should be readily apparent to those of ordinary skill in the art that various changes and modifications in form and detail may be made without departing from the spirit and scope of the present invention as set forth in the appended claims.

What is claimed is:

1. In a chemical-mechanical-polishing system having a platen and a polishing pad, an arrangement comprising:

a support pad disposed between said platen and said polishing pad, said support pad comprising:
a housing, said housing defining a chamber;
a matrix having voids therein, said matrix located within said chamber;
a fluid disposed within said chamber; and
said matrix permeable with respect to said fluid.

2. The arrangement of claim **1**, wherein said chamber is pressurized by said fluid, said fluid in at least one of a gaseous state, a gelatinous state, and a liquid state.

3. The arrangement of claim **2**, wherein pressure in said chamber is in a range of approximately 1 to 100 p.s.i.

4. The arrangement of claim **1**, wherein said matrix is coupled to said housing to limit deformation of said chamber.

5. In a chemical-mechanical-polishing system having a platen and a polishing pad, an arrangement comprising:

a support pad disposed between said platen and said polishing pad, said support pad comprising:
a housing, said housing defining a volume;
a webbing located within said volume and coupled to said housing to limit deformation of said volume; and
a fluid disposed within said volume.

6. The arrangement of claim **5**, wherein said housing is pressurized by said fluid.

7. The arrangement of claim **6**, wherein pressure in said volume is in a range of approximately 1 to 100 p.s.i.

8. The arrangement of claim **5**, wherein said webbing provides baffling within said volume of said housing.

9. In a chemical-mechanical-polishing system having a platen and a polishing pad, an arrangement comprising:

a support pad disposed between said platen and said polishing pad, said support pad comprising:
a pressurizable member having variable deformability, said pressurizable member providing an enclosure;
a matrix having voids therein, said matrix located within said enclosure;
a webbing located within said enclosure and coupled to said pressurizable member to limit deformation thereof;
a fluid disposed within said enclosure; and
said matrix permeable with respect to said fluid.

10. The arrangement of claim **9**, wherein said matrix is coupled to said pressurizable member to limit deformation of said enclosure.

11. The arrangement of claim **9**, further comprising at least one tube operatively coupled to deliver said fluid to said enclosure.

12. The arrangement of claim **9**, further comprising:

an inlet tube operatively coupled to deliver said fluid to said enclosure; and

an outlet tube operatively coupled to remove said fluid from said enclosure.

13. The arrangement of claim **12**, wherein said webbing provides baffling for regulating transmission of said fluid from said inlet tube to said outlet tube.

14. In a chemical-mechanical-polishing system having a platen and a polishing pad, an arrangement comprising:

a support pad disposed between said platen and said polishing pad, said support pad comprising:
a housing, said housing defining a volume;
an open-cell material located within said volume;
a fluid disposed within said volume;
an inlet tube operatively coupled to deliver said fluid to said volume;
a manifold operatively coupled to said inlet tube to receive said fluid and to distribute said fluid in said volume; and
an outlet tube operatively coupled to said manifold to remove said fluid from said volume.

15. The arrangement of claim **14**, wherein said open-cell material is configured to provide said manifold.

16. In a chemical-mechanical-polishing system having a platen and a polishing pad, a support pad comprising:

a housing, said housing having a top layer and at least one side layer;

a surface of said platen, said top layer, and said side layer in combination defining a space;

a fluid located within said space; and

a porous solid member, permeable with respect to said fluid, located in said space and coupled to said housing to limit deformation of said space.

17. In a chemical-mechanical-polishing system having a wafer carrier, a support pad comprising:

a flexible structural member, said flexible structural member having a bottom layer and at least one side layer;

a surface of said wafer carrier, said bottom layer, and said side layer in combination defining an enclosure;

a fluid located within said enclosure; and

a porous solid member, permeable with respect to said fluid, located within saud enclosure, said porous solid member coupled to said flexible structural member and to said wafer carrier to limit deformation of said enclosure.

18. In a chemical-mechanical-polishing system having a platen and a polishing pad, a support pad comprising:

a housing, said housing having a top layer and at least one side layer;

a surface of said platen, said top layer, and said side layer in combination defining a volume;

webbing located within said volume and coupled to said housing and said platen to limit deformation of said volume; and

a fluid located within said volume.

19. In a chemical-mechanical-polishing system having a wafer carrier, a support pad comprising:

a housing, said housing having a bottom layer and at least one side layer;

a surface of said wafer carrier, said bottom layer, and said side layer in combination defining a volume;

webbing located within said volume and coupled to said housing and said wafer carrier to limit deformation of said volume; and

a fluid located within said volume.

20. An apparatus for use in planarizing a semiconductor substrate assembly, comprising:

a chemical-mechanical-polishing pad;

a housing, said housing having a bottom layer and at least one side layer;

a surface of said chemical-mechanical-polishing pad, said bottom layer, and said side layer in combination defining a volume;

a fluid located within said volume; and

a porous solid member, permeable with respect to said fluid, located within said volume and coupled to said chemical-mechanical-polishing pad and said housing to limit expansion of said volume.

21. An apparatus for use in planarizing a semiconductor substrate assembly, comprising:

a chemical-mechanical-polishing pad;

a housing, said housing having a bottom layer and at least one side layer;

a surface of said chemical-mechanical-polishing pad, said bottom layer, and said side layer in combination defining a volume;

webbing located within said volume and coupled to said housing and said chemical-mechanical-polishing pad to limit expansion of said volume; and

a fluid located within said volume.

22. In a chemical-mechanical-polishing system having a platen and a polishing pad, an arrangement comprising;

a support pad disposed between said platen and said polishing pad, said support pad comprising:

a polymeric open-cell foam, said polymeric open-cell foam having a skin, said skin defining an enclosed region;

a fluid disposed within said enclosed region.

23. In a chemical-mechanical-polishing system having a platen and a polishing pad, an arrangement comprising:

a support pad disposed between said platen and said polishing pad, said support pad comprising:

elastomeric open-cell foam, said elastomeric open-cell foam having a skin, said skin defining an enclosed region; and

a fluid disposed within said enclosed region.

* * * * *

UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO. : 6,312,558 B1
DATED : November 6, 2001
INVENTOR(S) : Moore

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1,
Line 18, delete "place" and insert -- placed --, therefor.

Column 2,
Line 41, delete "systems" and insert -- system --, therefor.

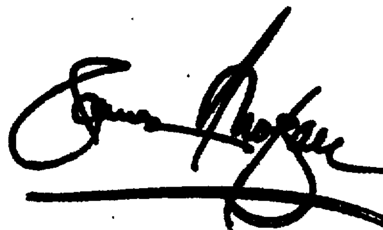
Column 5,
Line 1, delete "effected" and insert -- affected --, therefor.

Column 6, claim 17,
Line 53, delete "saud" and insert -- said --, therefor.

Signed and Sealed this

Twenty-sixth Day of March, 2002

Attest:



JAMES E. ROGAN
Director of the United States Patent and Trademark Office

Attesting Officer